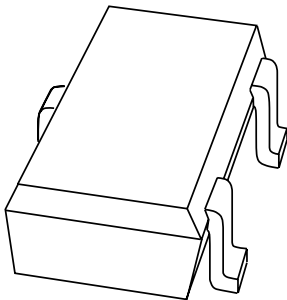


# DATA SHEET



## **BC846W; BC847W; BC848W** NPN general purpose transistors

Product specification  
Supersedes data of 1999 Apr 23

2002 Feb 04

## NPN general purpose transistors

## BC846W; BC847W; BC848W

### FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 65 V).

### APPLICATIONS

- General purpose switching and amplification.

### DESCRIPTION

NPN transistor in a SOT323 plastic package.  
 PNP complements: BC856W, BC857W and BC858W.

### MARKING

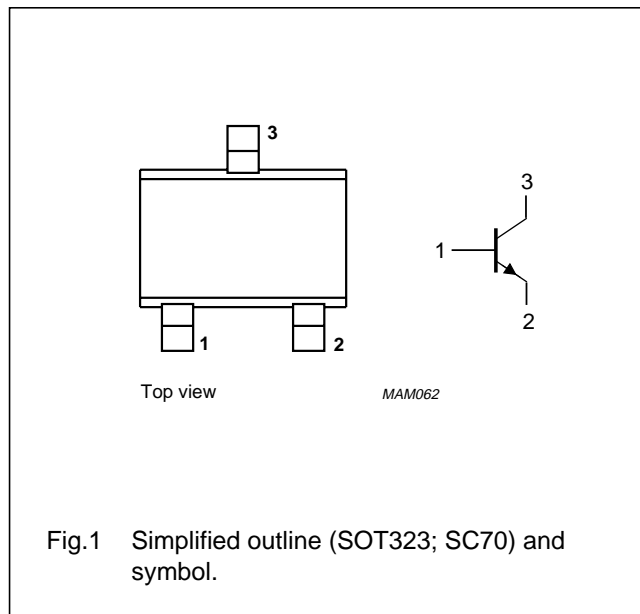
TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BC846W	1D*
BC846AW	1A*
BC846BW	1B*
BC847W	1H*
BC847AW	1E*
BC847BW	1F*
BC847CW	1G*
BC848W	1M*

### Note

1. \* = -: made in Hong Kong.  
 \* = t: made in Malaysia.

### PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



## NPN general purpose transistors

## BC846W; BC847W; BC848W

**LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter			
	BC846W		–	80	V
	BC847W		–	50	V
	BC848W	–	30	V	
$V_{CEO}$	collector-emitter voltage	open base			
	BC846W		–	65	V
	BC847W		–	45	V
	BC848W	–	30	V	
$V_{EBO}$	emitter-base voltage	open collector			
	BC846W; BC847W		–	6	V
	BC848W	–	5	V	
$I_C$	collector current (DC)		–	100	mA
$I_{CM}$	peak collector current		–	200	mA
$I_{BM}$	peak base current		–	200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$ ; note 1	–	200	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	150	°C
$T_{amb}$	operating ambient temperature		–65	+150	°C

**Note**

1. Transistor mounted on an FR4 printed-circuit board.

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	in free air; note 1	625	K/W

**Note**

1. Transistor mounted on an FR4 printed-circuit board.

## NPN general purpose transistors

## BC846W; BC847W; BC848W

**CHARACTERISTICS**

$T_{amb} = 25\text{ °C}$ ; unless otherwise specified.

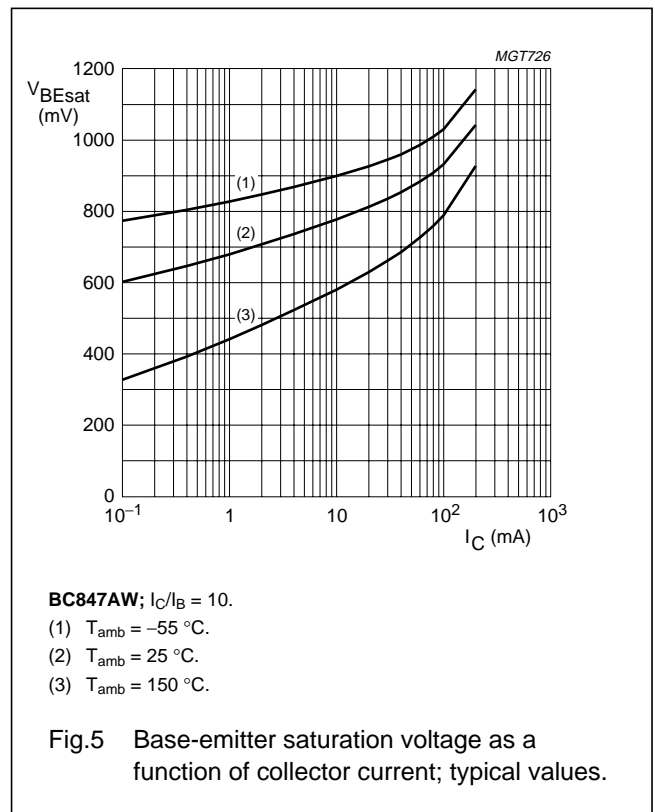
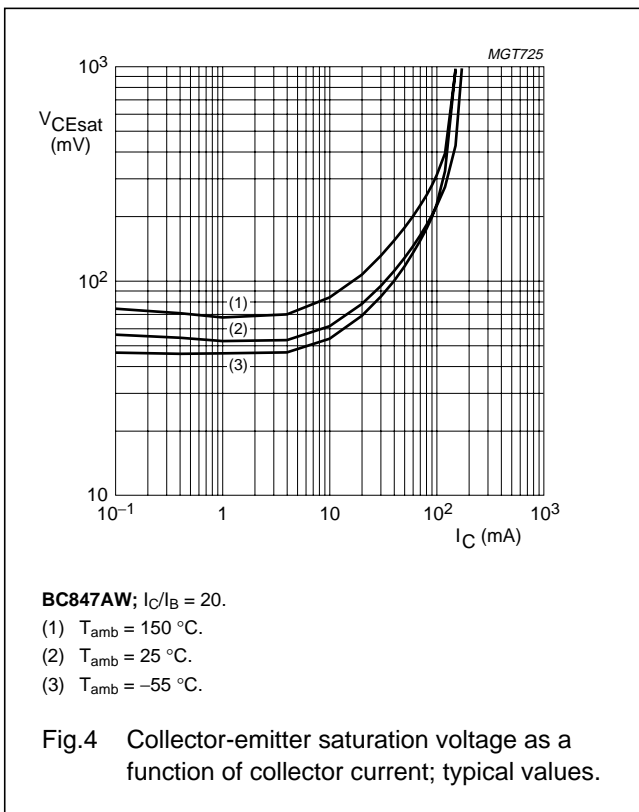
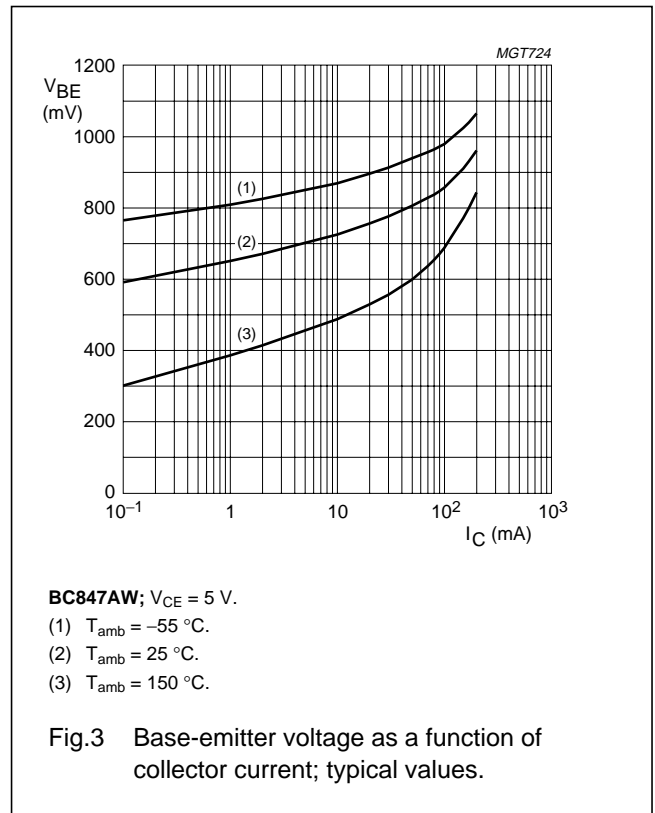
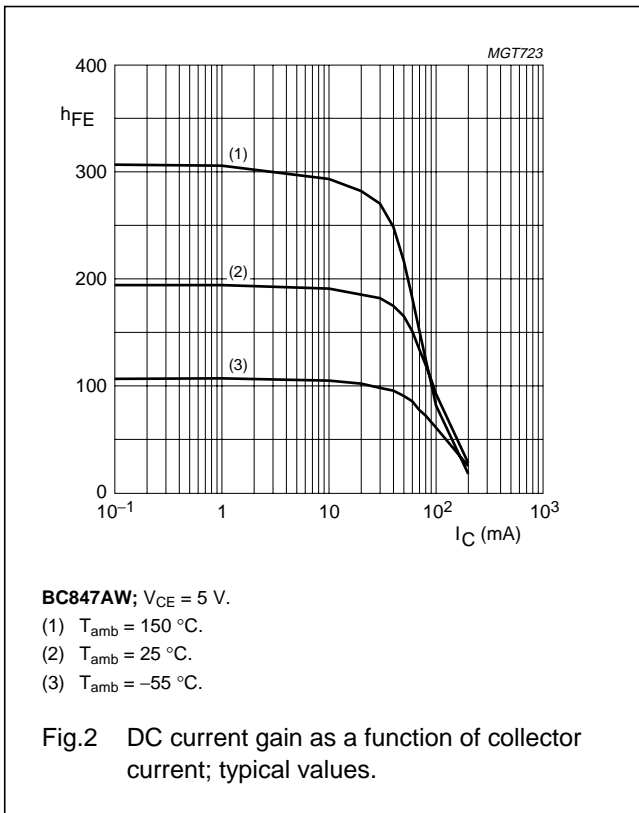
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 30\text{ V}; I_E = 0$	–	–	15	nA
		$V_{CB} = 30\text{ V}; I_E = 0;$ $T_j = 150\text{ °C}$	–	–	5	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0$	–	–	100	nA
$h_{FE}$	DC current gain	$I_C = 10\text{ }\mu\text{A}; V_{CE} = 5\text{ V}$	–	90	–	
	BC846AW; BC847AW					
$h_{FE}$	DC current gain	$I_C = 2\text{ mA}; V_{CE} = 5\text{ V}$	110	–	450	
	BC846W					
	BC847W; BC848W					
	BC846AW; BC847AW					
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$	–	90	250	mV
		$I_C = 100\text{ mA}; I_B = 5\text{ mA};$ note 1	–	200	600	mV
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$	–	700	–	mV
		$I_C = 100\text{ mA}; I_B = 5\text{ mA};$ note 1	–	900	–	mV
$V_{BE}$	base-emitter voltage	$I_C = 2\text{ mA}; V_{CE} = 5\text{ V}$	580	660	700	mV
		$I_C = 10\text{ mA}; V_{CE} = 5\text{ V}$	–	–	770	mV
$C_c$	collector capacitance	$V_{CB} = 10\text{ V}; I_E = I_e = 0;$ $f = 1\text{ MHz}$	–	–	3	pF
$f_T$	transition frequency	$V_{CE} = 5\text{ V}; I_C = 10\text{ mA};$ $f = 100\text{ MHz}$	100	–	–	MHz
F	noise figure	$I_C = 200\text{ }\mu\text{A}; V_{CE} = 5\text{ V};$ $R_S = 2\text{ k}\Omega; f = 1\text{ kHz};$ $B = 200\text{ Hz}$	–	–	10	dB

**Note**

1. Pulse test:  $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$ .

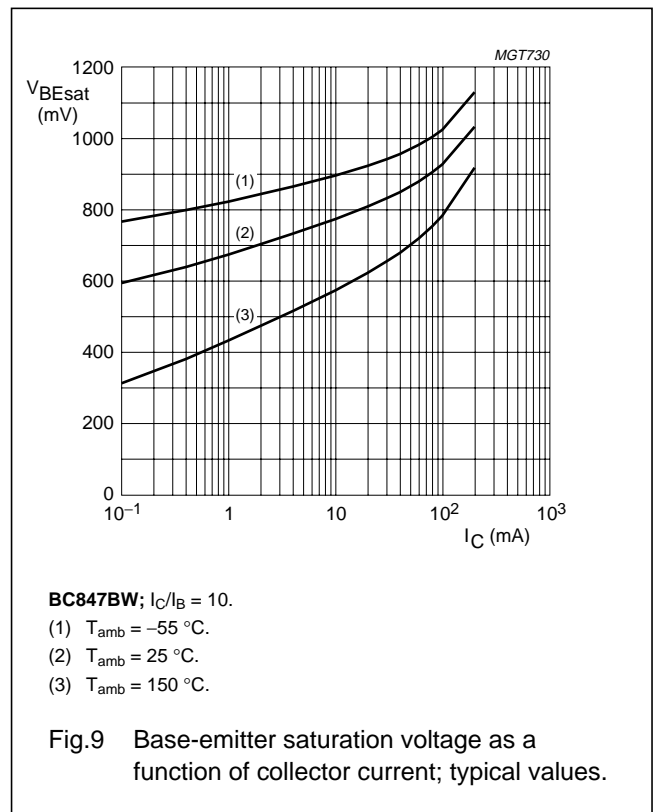
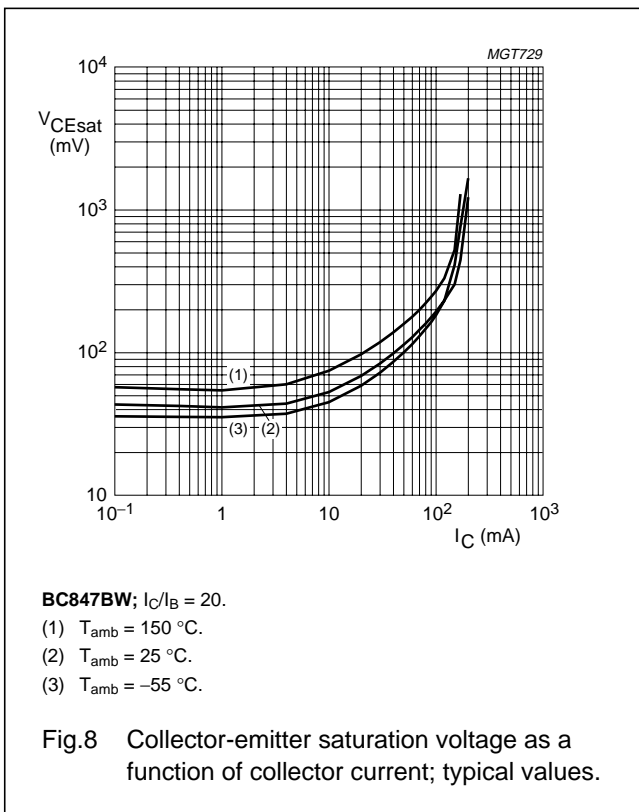
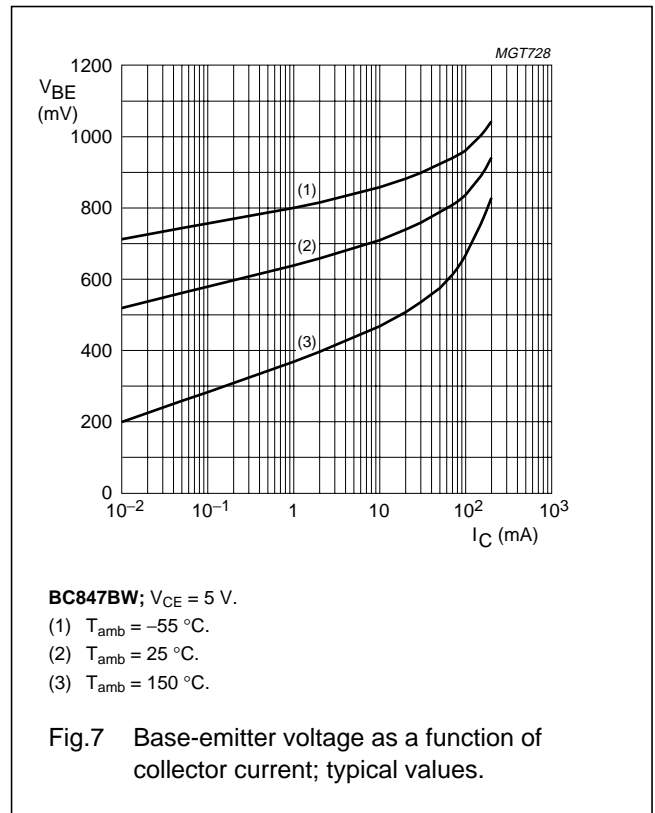
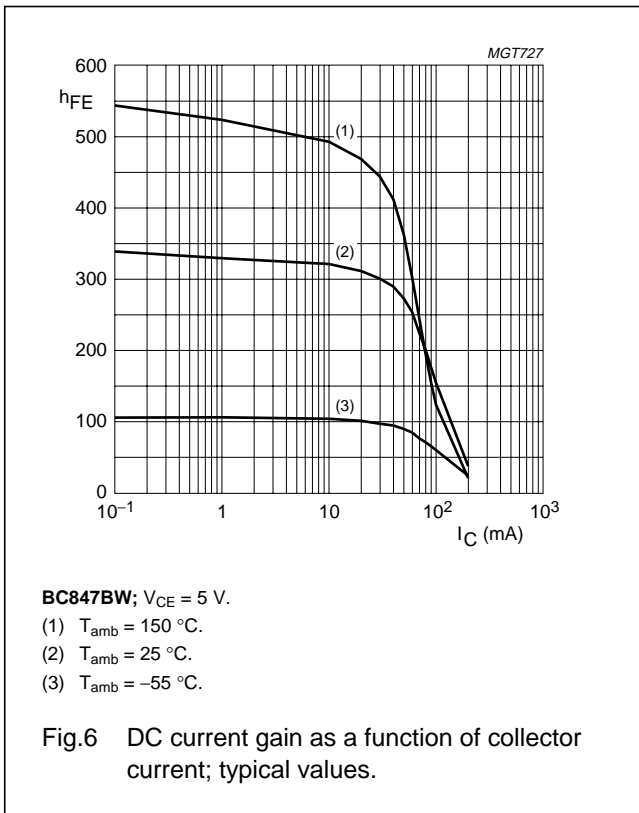
NPN general purpose transistors

BC846W; BC847W; BC848W



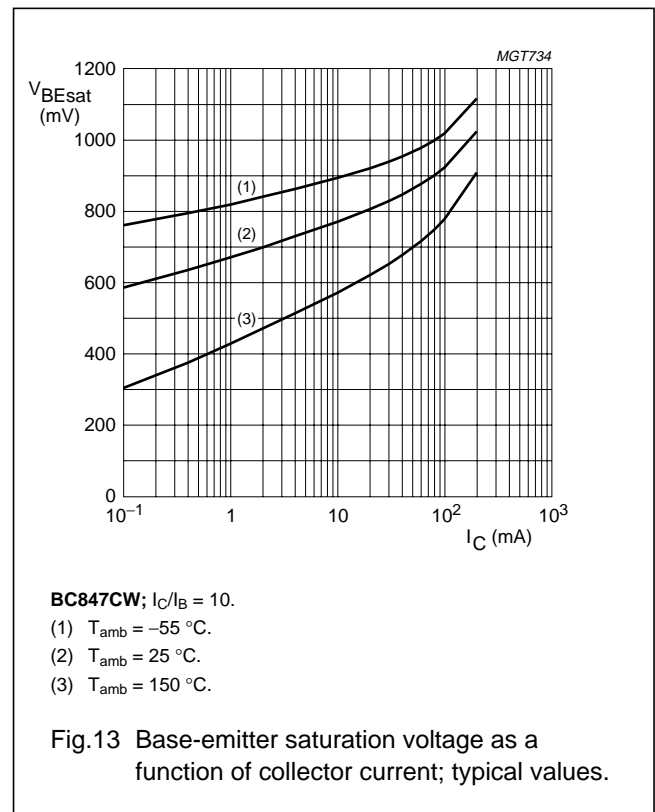
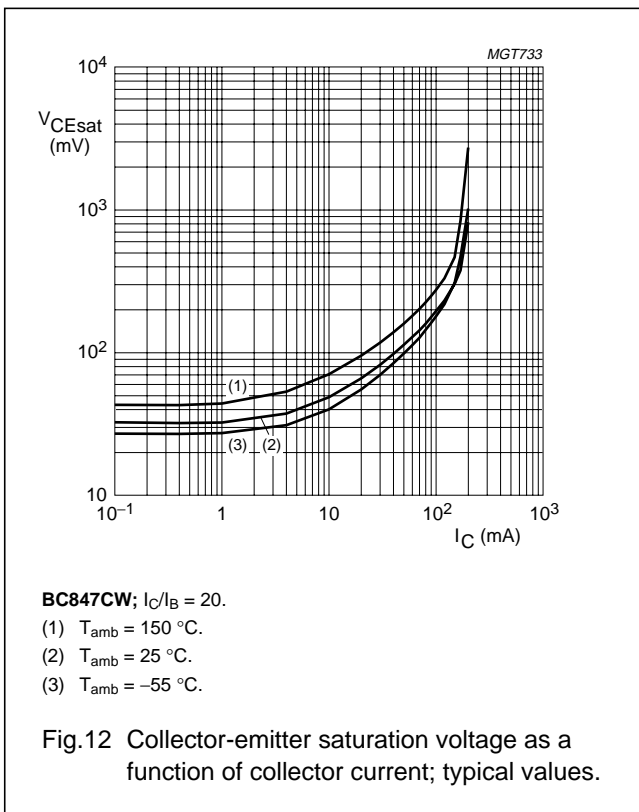
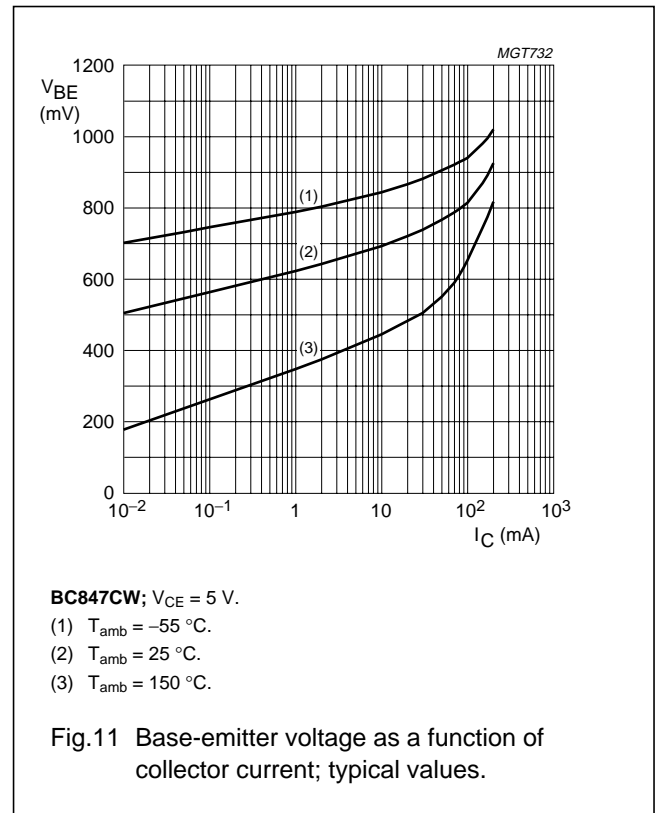
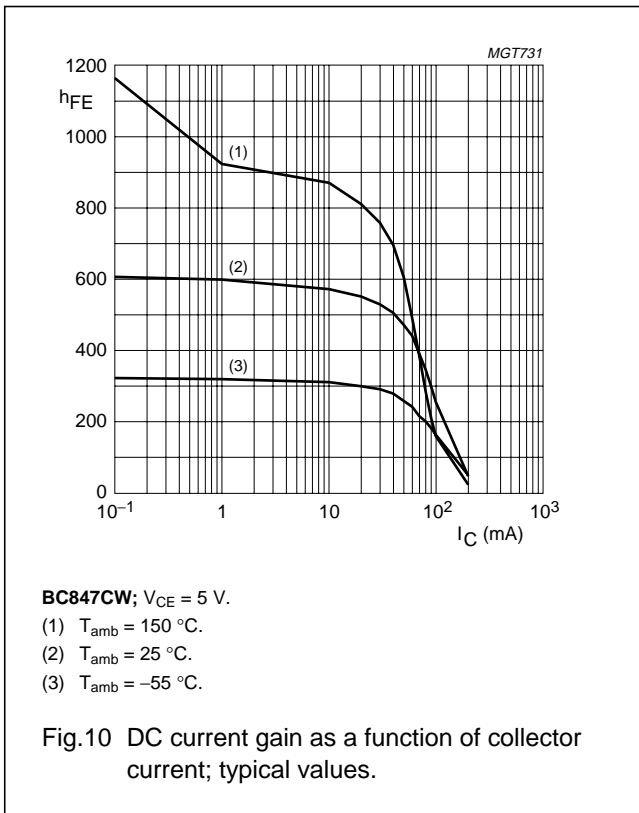
NPN general purpose transistors

BC846W; BC847W; BC848W



NPN general purpose transistors

BC846W; BC847W; BC848W



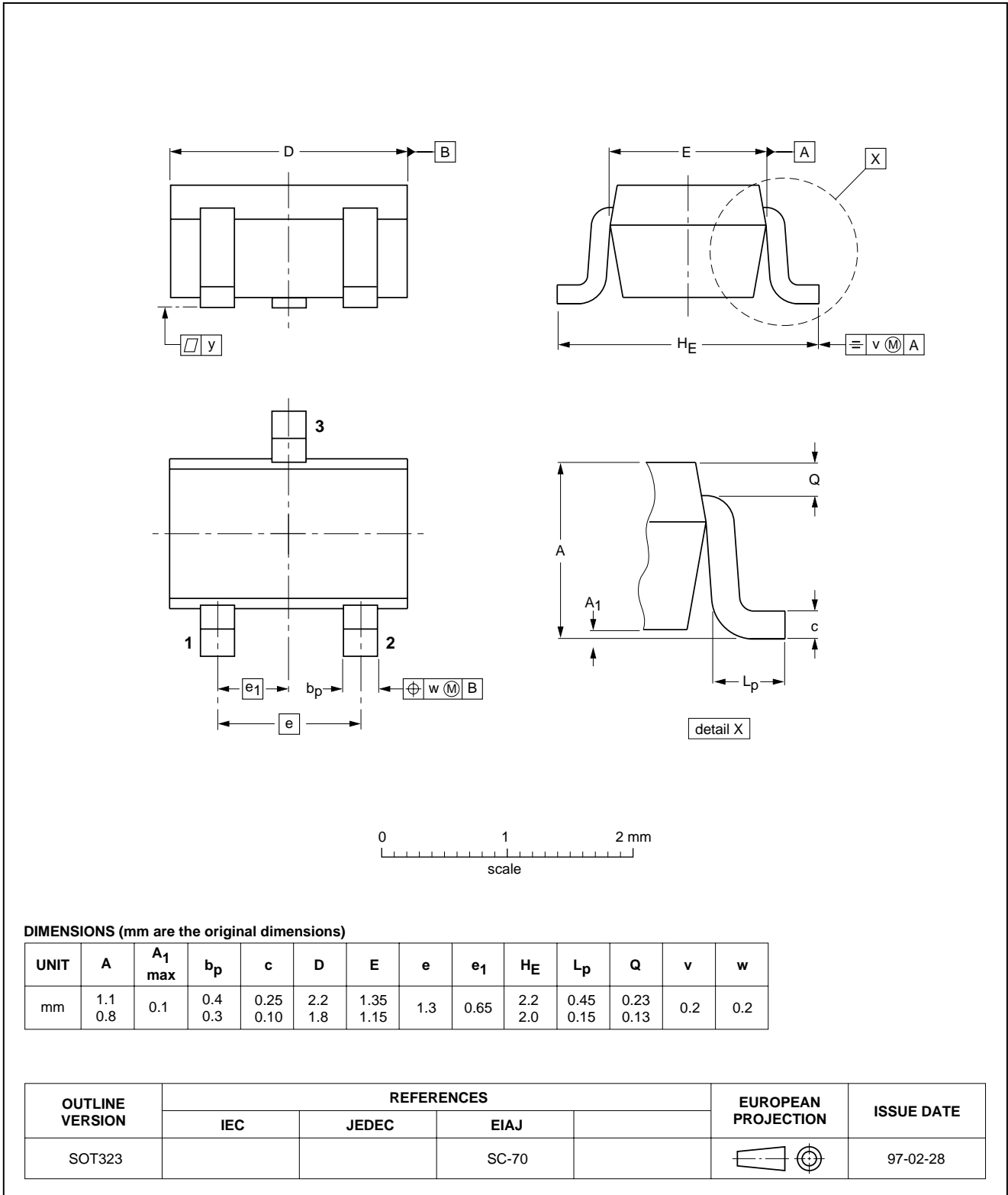
NPN general purpose transistors

BC846W; BC847W; BC848W

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323





## NPN general purpose transistors

## BC846W; BC847W; BC848W

## DATA SHEET STATUS

DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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NPN general purpose transistors

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**NOTES**

NPN general purpose transistors

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**NOTES**

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Printed in The Netherlands

613514/04/pp12

Date of release: 2002 Feb 04

Document order number: 9397 750 09166

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